Littelfuse Power

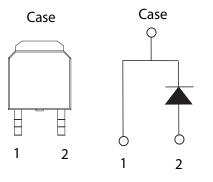
GEN2 SiC Schottky Diode LSIC2SD065C16A, 650 V, 16 A, TO-252-2L (DPAK)

LSIC2SD065C16A 650 V, 16 A SiC Schottky Barrier Diode



Circuit Diagram TO-252-2L (DPAK)

Maximum Ratings



Description

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes series are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

Features

- AEC-Q101 qualified
- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- Excellent surge capability

HE

RoHS

Po

- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

Applications

supplies

supplies

 Boost diodes in PFC or DC/DC stages

• Uninterruptible power

- Switch-mode power
- Solar inverters
- Industrial motor drives
- EV charging stations

Environmental

- Littelfuse "RoHS" logo = RoHS RoHS conform
- Littelfuse "HF" logo = **HF** Halogen Free
- Littelfuse "Pb-free" logo = Pb-free lead plating

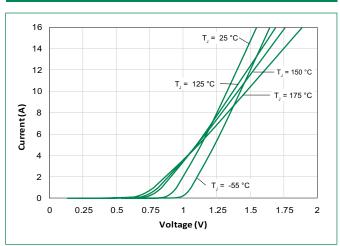
Maximum natings						
Characteristics	Symbol	Conditions	Value	Unit		
Repetitive Peak Reverse Voltage	V _{RRM}	-	650	V		
DC Blocking Voltage	V _R	T _J = 25 °C	650	V		
Continuous Forward Current		T _c = 25 °C	38			
	I _F	T _c = 135 °C	17.2	A		
		T _c = 140 °C	16			
Non-Repetitive Forward Surge Current	I _{FSM}	$T_c = 25 \text{ °C}, T_p = 10 \text{ ms}, \text{ Half sine pulse}$	70	A		
Power Dissipation	D	$T_c = 25 \text{ °C}$	125	10/		
	P _{Tot}	$T_c = 110 \text{ °C}$	54	A W °C		
Operating Junction Temperature	TJ	-	-55 to 175	°C		
Storage Temperature	T _{stg}	-	-55 to 150	°C		
Soldering Temperature (reflow MSL1)	T _{sold}	-	260	°C		

Electrical Characteristics						
Characteristics Sy			Value			
	Symbol	Conditions	Min.	Тур.	Max.	Unit
Forward Voltage		I _F = 16 Α, Τ _J = 25 °C	-	1.5	1.8	V
	V _F	I _F = 16 A, Τ _J = 175 °C	-	1.85	-	V
Reverse Current		V _R = 650 V , T _J = 25 °C	-	<1	50	μΑ
	R	V _R = 650 V , T _J = 175 °C	-	55	-	
Total Capacitance		$V_{R} = 1 V$, f = 1 MHz	-	730	-	μA pF
	С	V _R = 200 V, f = 1 MHz	-	92	-	
		V _R = 400 V, f = 1 MHz	-	66	-	
Total Capacitive Charge	Q _c	$V_{R} = 400 \text{ V}, \ \mathbf{Q}_{c} = \int_{0}^{V_{R}} C(V) dV$	-	48	-	nC

Footnote: $T_J = +25$ °C unless otherwise specified

Figure 1: Typical Foward Characteristics

Thermal Characteristics						
Characteristics	Symbol	Value	Unit			
Thermal Resistance	R _{ejc}	1.2	°C/W			





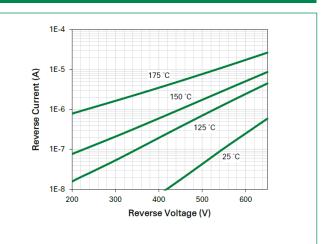


Figure 3: Power Derating

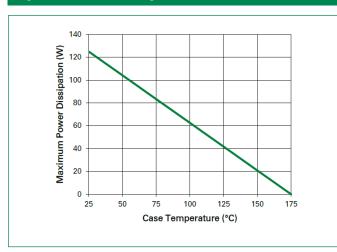


Figure 5: Capacitance vs. Reverse Voltage

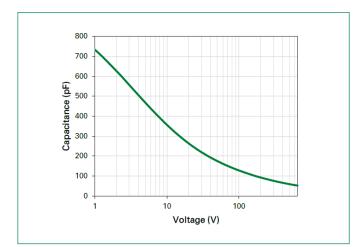


Figure 7: Stored Energy vs. Reverse Voltage

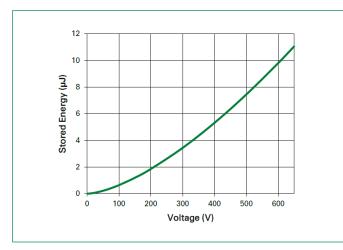


Figure 4: Current Derating

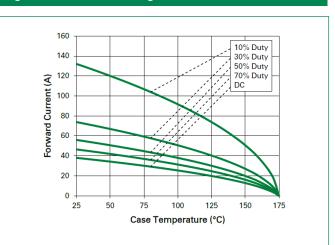


Figure 6: Capacitive Charge vs. Reverse Voltage

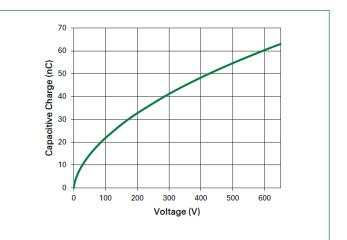
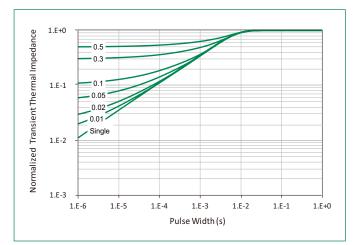
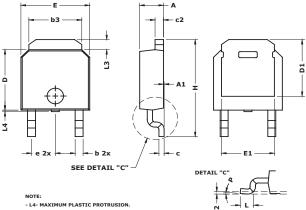
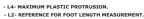


Figure 8: Transient Thermal Impedance

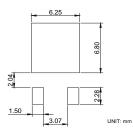


Dimensions TO-252-2L (DPAK)



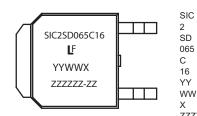


Recommended Solder Pattern Layout



Symbol		Inches		Ν	Millimeters		
Symbol	Min	Nom	Max	Min	Nom	Max	
А	0.085	0.090	0.095	2.16	2.29	2.41	
A1	0	0.003	0.005	0	0.08	0.13	
b	0.025	0.030	0.035	0.64	0.76	0.89	
b3	0.195	0.200	0.215	4.95	5.08	5.46	
С	0.018	0.020	0.024	0.46	0.51	0.61	
C2	0.018	0.032	0.035	0.46	0.81	0.89	
D	0.235	0.240	0.245	5.97	6.10	6.22	
D1	0.205	-	-	5.21	-	-	
Е	0.250	0.260	0.265	6.35	6.60	6.73	
E1	0.170	-	-	4.32	-	-	
е	0	.090 BSC		2.29 BSC			
Н	0.370	0.387	0.410	9.40	9.83	10.41	
L	0.040	0.045	0.050	1.02	1.14	1.27	
L2	0.010 BSC				0.25 BSC		
L3	0.035	-	0.050	0.89	-	1.27	
L4	0	-	0.006	0	-	0.15	
Р	0°	-	8 °	0°	-	8 °	

Part Numbering and Marking System



)	= SiC Diode
	= Gen2
	= Schottky Diode
5	= Voltage Rating (650 V)
	= TO-252-2L (DPAK)
	= Current Rating (16 A)
	= Year
v	= Week



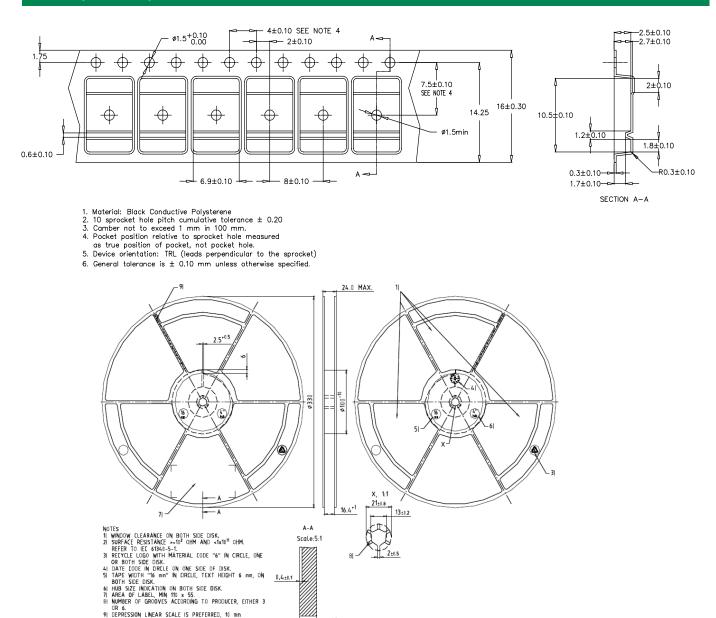
X = Special code ZZZZZZ-ZZ = Lot Number = Special code

Packing Options

Part Number	Marking	Packing Mode	M.O.Q
LSIC2SD065C16A	SIC2SD065C16	Tape and Reel	2500

Carrier Tape & Reel Specification TO-252-2L (DPAK)

UR 6. 9) DEPRESSION LINEAR SCALE IS PREFERRED, 10 mm INTERVAL, HEIGHT OF LETTERING 3 mm. NON CRITICAL DIMENSIONS ACCORDING TO PRODUCER.



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